Product data sheet

1. General description

Hyperfast power diode in a 2-lead TO220 plastic package





2. Features and benefits

- Low leakage current
- · Low thermal resistance
- · Low reverse recovery current
- · Reduces switching losses in associated MOSFET or IGBT

3. Applications

- Active PFC in air conditioner/EV charger/PV
- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- · Half-bridge/full-bridge switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values		Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			600		V	
I _{F(AV)}	average forward current	$δ$ = 0.5 ; square-wave pulse; $T_{mb} \le 134$ °C; Fig. 1; Fig. 2; Fig. 3		15		А	
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 134 °C; square-wave pulse		30		A	
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; <u>Fig. 4</u>		200		А	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		220		Α	
Symbol	Parameter	Conditions	Notes	Min Typ Max		Unit	
Static ch	aracteristics						
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.92	2.35	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.27	1.70	V
Dynamic	characteristics					,	
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 200 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	16	-	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		к <u>—</u> А
2	А	anode		001aaa020
mb	mb	mounting base; connected to cathod		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing guantity	. •	Package issue date
BYC15M-600P	TO220-2L	BYC15M-600PQ	Tube	50	TO220d-2L	13-Oct-2022

7. Marking

Table 4. Marking codes

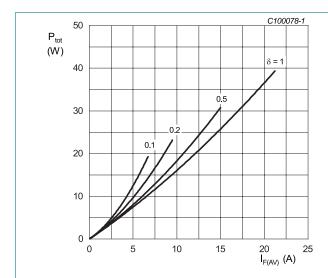
Type number	Marking codes
BYC15M-600P	BYC15M 600P

8. Limiting values

Table 5. Limiting values

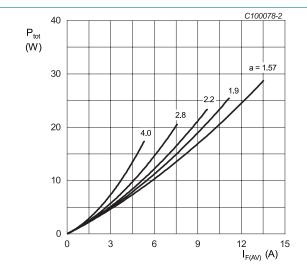
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			600	V
V _{RWM}	crest working reverse voltage			600	V
V _R	reverse voltage	DC		600	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 134 °C; Fig. 1; Fig. 2; Fig. 3		15	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 134 °C; square-wave pulse		30	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		200	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		220	Α
T _{stg}	storage temperature			-65 to 175	°C
T _j	junction temperature			-65 to 175	°C



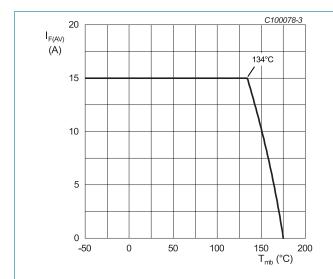
 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.384 \text{ V; R}_s = 0.0223 \Omega$

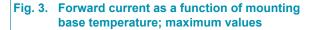
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.384 V; R_s = 0.0223 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





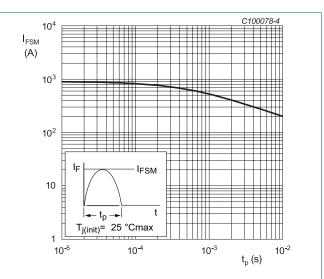


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	1.33	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

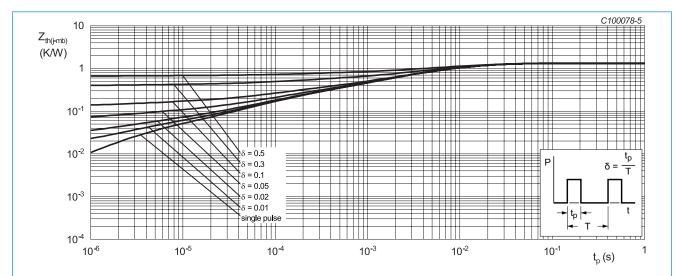
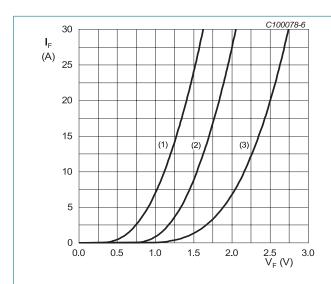


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics		•				
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.92	2.35	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.27	1.70	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C		-	0.71	10	μA
		V _R = 600 V; T _j = 150 °C		-	-	0.5	mA
Dynamic	characteristics		-1				
Q _r	reverse charge	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$		-	75	-	nC
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_1 = 125 \text{ °C}; Fig. 7$		-	204	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_1 = 25 ^{\circ}\text{C}; Fig. 7$		-	16	-	ns
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_I = 25 \text{ °C}; Fig. 7$		-	26	-	ns
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_1 = 125 \text{ °C}; Fig. 7$		-	38	-	ns
I _{RM}	peak reverse recovery current	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_J = 25 ^{\circ}\text{C}; Fig. 7$		-	5.7	-	А
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$		-	10.8	-	А



 V_o = 1.384 V; R_s = 0.0223 Ω

(1) T_i = 150 °C; typical values

(2) T_i = 150 °C; maximum values

(3) T_i = 25 °C; maximum values



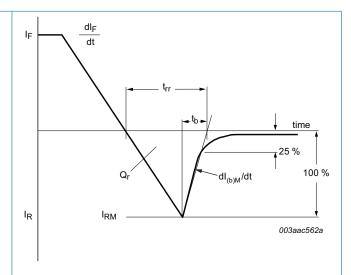
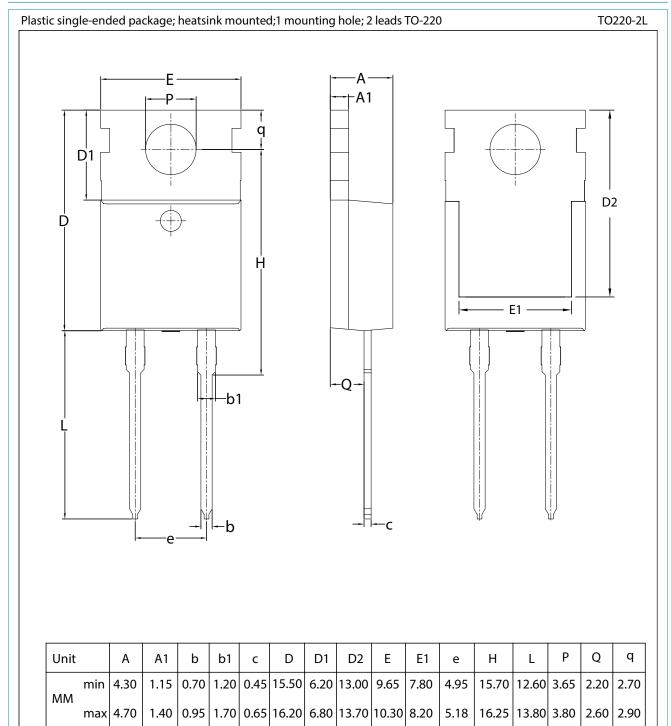


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



Note:

1. All dimensions don't include mold flash and metal protrusion.

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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